Thick Film Hybrid IC



# STK681-050 **Bidirectional DC Brush-Type** Motor Driver (I<sub>O</sub>=5A)

### **Overview**

The STK681-050 is a bidrectional DC brush-type motor driver IC with brake function that incorporates MOSFET power elements.

### Applications

- PPC drum and scanner motor drivers
- LBP drum motor drivers
- · Printer head and carriage motor drivers
- General DC motor applications

### Features

- H-bridge output stage configuration employing 4 **MOSFETs**
- Independent TTL/CMOSlevel control for each MOSFET (4-pin control)
- External signal control of forward, reverse and brake opreration
- MOSFETs supporting 12A peak starting current and 13.5A peak brake current (F3 and F4 ON)
- DC input supporting saturation operation
- Only 1 charge pump electrolytic capacitor required, compared with the STK6875 which requires 2

### **Specifications**

Allowable power dissipation 1

Allowable power dissipation 2

### **Maximum Ratings** at $Ta = 25^{\circ}C$ Parameter Symbol Conditions Ratings 50 V<sub>CC</sub>1 max No signal Maximum supply voltage 1 Maximum supply voltage 2 V<sub>CC</sub>2 max 10 No signal Maximum input voltage Vin max Pins 1, 3, 12, 14, 15 ±10 Maximum motor starting current IO peak 1 pulse, pulse width=70ms 12 Maximum motor brake current 1 IOB1 peak 1 pulse, pulse width=70ms 12 (F1 and F2 ON) 1 pulse, pulse width=25ms 16 Maximum motor brake current 2 IOB2 peak (F3 and F4 ON) 1 pulse, pulse width=100ms 13.5

No heatsink, total loss

Arbitrary large heatsink, per MOSFET

Pd1 max

Pd2 max

5.2 25 W

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Unit V

V

V

А

А

А

А

W

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### Package Dimensions

unit:mm



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Parameter	Symbol	Conditions	Ratings	Unit
Thermal resistance	ө ј-с	Per MOSFET	5	°C/W
Junction temperature	Tj max	Per MOSFET	150	°C
Operating substrate temperature	Tc max		105	°C
Storage temperature	Tstg		-40 to +125	°C

### Allowable Operating Ranges at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage 1	V <sub>CC</sub> 1	With signal	18 to 42	V
Supply voltage 2	V <sub>CC</sub> 2	With signal	4.75 to 7.00	V
Input voltage	Vin	Pins 1, 3, 12, 14, 15	-7 to +7	V
Motor output current	IO	PWM frequency fp=25kHz	5	А
Motor starting current	IOD	1 pulse, t=200ms	8	А
Motor brake current 1 (F1 and F2 ON)	I <sub>OB</sub> 1	Triangle wave, 1 pulse, pulse width=100ms	11	А
Motor brake current 2 (F3 and F4 ON)	I <sub>OB</sub> 2	Triangle wave, 1 pulse, pulse width=100ms	13.5	А
PWM frequency	fP		0 to 30	kHz
CLK input frequency	<sup>f</sup> CLK	40 to 60% duty	10 to 30	kHz
Sensing voltage	VS	Between pins 4/5 and ground	0 to 0.6	V
Gate input voltage	VIG	Between pins 3/12 and SG	V <sub>CC</sub> <sup>2</sup>	V
MOSFET withstand voltage	VDSS	F1, F2, F3, F4	60	V

## Electrical Characteristics at Ta = 25°C, V<sub>CC</sub>1=24V, V<sub>CC</sub>2=5.0V, f<sub>CLK</sub>=25kHz

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Output saturation voltage 1	Vst1	I <sub>O</sub> =5A, F1, F2		0.75	1.05	V
Output saturation voltage 2	Vst2	I <sub>O</sub> =5A, F3, F4		0.43	0.65	V
Output leakage current	۱L	Pins 12, 14, 15=0.8V, pin 3 open			100	
		Pins 3, 14, 15=0.8V, pin 12 open			100	μA
Supply current	lcco	Pins 3, 12, 14, 15=0.8V	2.0	2.7	4.0	mA
Input ON voltage	VIH	Pins 1, 14, 15	2.0		V <sub>CC<sup>2</sup></sub>	V
Input OFF voltage	VIL	Pins 1, 3, 12, 14, 15			0.80	V
Input ON current	Iн	Pins 1, 14, 15 (V <sub>IH</sub> =2.7V)		0.21	0.42	mA
Input OFF current	۱ <sub>IL</sub>	Pins 3, 12 (V <sub>IL</sub> =0.4V)		1.0	1.2	mA
Diode forward-bias voltage	٧ <sub>F</sub>	I <sub>F</sub> =5A		1.0	1.4	V
Turn ON delay time 1	<sup>t</sup> d-ON <sup>1</sup>	F1, F2 (I <sub>O</sub> =5A)		0.6		μs
Turn OFF delay time 1	td-OFF1	F1, F2 (I <sub>O</sub> =5A)		3.9		μs
Turn ON delay time 2	<sup>t</sup> d-ON <sup>2</sup>	F3, F4 (I <sub>O</sub> =5A)		0.2		μs
Turn OFF delay time 2	td-OFF <sup>12</sup>	F3, F4 (I <sub>O</sub> =5A)		0.6		μs

Note : All tests made using a constant-voltage supply.

**Block Diagram** 



Test Circuit Vst1, Vst2, I<sub>CCO</sub>, I<sub>L</sub>



Test parameter	Input conditions					
	Pin 14	Pin 15	Pin 12	Pin 13		
Vst1-1	High	Low	Low	Open		
Vst1-2	Low	High	Open	Low		
Vst2-1	Low	High	Open	Low		
Vst2-2	High	Low	Low	Open		
Icco	Low	Low	Low	Low		
IL1	Low	Low	Low	Open		
IL2	Low	Low	Open	Low		
High : V <sub>IH</sub> =2.0V Low : V <sub>IL</sub> =0.8V						





Mode	IN A	IN C	IN B	IN D
Standby (before drive)	Low	Low	Low	Low
CW	High	Low	Low	PWM
CCW	Low	High	PWM	Low
Brake	Low	Low	V <sub>CC</sub> 2	V <sub>CC</sub> 2
Inhibit mode	High	×	High	×
	×	High	×	High

High :  $V_{IH} \ge 2.7V$ 

Low :  $V_{IL} \le 0.4V$ High level during PWM operation= $V_{CC}2$  $\times$ =don't care

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